Diamond for High Energy Radiation and Particle Detection

- How diamond works as a sensor material
 - Growth, signal, characterisation, manufacture
- Radiation tolerance
 - Tracker signals, irradiations, damage scaling
- Applications
 - Beam monitors: ATLAS BCM, BaBar, CDF, CMS
 - Pixel detectors: CMS PLT, ATLAS DBM



William Trischuk University of Toronto on behalf of the RD42 Collaboration July 22, 2011

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Spokespersons

Over 100 Collaborators

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from 32 institutions

CVD Diamond as a Particle Detector

• Charge deposited Q_0 ; collected Q

• Microwave growth reactor



$$Q = \frac{\mathsf{d}}{t} \ Q_0$$

- d is the Charge Collection Distance
- *t* is the sensor thickness



- Carrier velocity saturates at $|\vec{E}| \rightarrow 1V/\mu m$
- Typical operating point for sensors
- Diamond synthesis from plasma

Examples of CVD Material



Surface image of pCVD sample (Courtesy Element6)



- pCVD diamond wafer
- Dots are on 1 cm grid
- High quality wafers grown 12 cm in diameter
- Best material from wafers grown up to 2 mm thick

Radiation Tolerance of Diamond Sensors

Typically tested as strip tracker

Pulse height from irradiated tracker





- Use long (2 μ s) shaping time for precision materials studies
- After $1.4 \times 10^{15} \text{ p/cm}^2$ signal uniform/well separated from pedestal
 - 99 % of hits have more than 2500 electrons signal
 - Most probable signal 6000 electrons at 1 V/ μ m

24 GeV Proton Irradiations

- Have irradiated:
 - pCVD samples to $1.8\times10^{16}~\text{p/cm}^2$
 - scCVD samples to $5\times 10^{15}~\text{p/cm}^2$
- Characterise signal at intermediate fluences

- Default $E = 1 \text{ V/}\mu\text{m}$
- Green at $E = 2 \text{ V/}\mu\text{m}$
- Align by shifting $-3.8 \times 10^{15} \text{ p/cm}^2$

This pCVD material \equiv scCVD material **after** $\approx 3.8 \times 10^{15} \text{ p/cm}^2$

- pCVD and scCVD follow same damage curve:
 - $1/d = 1/d_0 + k\phi$

 $k pprox 0.7 imes 10^{-18}$ $\mu m^{-1} \, \mathrm{cm}^2$



Irradiations with Lower Energy Protons





- 800 MeV protons (Los Alamos):
 1.9 times 24 GeV protons
- 70 MeV protons (Sendai):
 2.9 times 24 GeV protons
- 25 MeV protons (Karlsruhe):
 4.7 times 24 GeV protons

Ultimate Fluence Tests: Very Forward Calorimetry

- Ultimate radiation test environment found in forward calorimetry
- MIP efficiency not as important as uniformity (resolution)
- Irradiated with up to 500 MeV protons (TRIUMF) to fluences $\geq 10^{17}$



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Applications of Diamond Sensors

- Several exciting applications for diamond sensors
 - High Energy Physics
 - Heavy Ion beam diagnostics
 - Synchrotron light source beam monitoring
 - Neutron and α detection
- Here I will discuss
 - Beam monitoring at
 - * LHC: ATLAS Beam Conditions Monitor
 - Pixel detector prototypes for LHC tracker upgrades
 - * CMS Pixel Luminosity Telescope
 - * ATLAS **Diamond Beam Monitor**

ATLAS Beam Conditions Monitor

• ATLAS BCM uses time-of-flight to distinguish collisions ($\Delta t = 0$) from background ($\Delta t = \pm 12$ ns)



- Supported in pixel space-frame
 - 1.9m from interaction point



- Use diamond sensors
 - 10x faster response and 10x more radiation hard than silicon
- Very fast, rad hard InGaP front end amplifier gives sub-ns resolution

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ATLAS BCM Performance

- Triggered abort in March 2010
- 3/4 stations on both sides of IP



- Sensitivity attenuated by 1/100
- Handful of abort conditions in 2011
- Analysing passively, prior to reintegration in LHC abort logic

• BCM provides online luminosity



- Pile-up insensitive to $\mathcal{L}\approx 10^{34}$
- Provides automatic feedback after every beam-dump (\approx 1000/year)

CMS Pixel Luminosity Telescope

- Stand-alone luminosity monitor
 - Eight 3-plane pixel telescopes at each side of CMS
 - $0.4 \times 0.4 \text{ cm}^2$ single crystal sensors at r = 4.8 cm, z = 175 cm
- Count 3-fold coincidences "fast-or" (40 MHz)
- Full pixel readout (tracking) (1 kHz)
- 1% bunch-by-bunch relative luminosity precision possible in minutes



PLT plane



Cassette for 12 planes



CMS PLT Construction Status

- Producing 60 planes (48 installed)
 - 57/80 sensors good (71%)
 - Failures replaced by vendor
- 40/59 modules assembled and working (70%)
- Full system test in beam now
- Plan to install in 2012



Diamond Beam Monitor

- Diamonds were a candidate sensor for ATLAS IBL upgrade
- Eight 3-plane telescopes around ATLAS interaction point
- Use enhanced spatial resolution to
 - Complement timing precision from BCM
 - Provide luminosity and beam-spot monitoring
- Install with ATLAS IBL in 2013



Current State of the ATLAS DBM

- Four modules assembled at IZM
 - 21x18 mm² sensors from DDL
 - 27k pixels $50\times 250 \mu m^2$
- Bumps look good in x-ray



Modules under test in lab now



• First source signals seen



• Test in beam in early August

Diamond Detector Systems in HEP



Summary

- Ever improving understanding of radiation damage in diamond
 - Quantifying damage from different species of particles
 - Beginning to understand the source of damage mechanisms
- Application in all LHC experiments, the machine itself and beyond
- Pixel modules are being assembled in industry
- Diamond trackers should start to appear in the next few years
- Promising for future LHC upgrades at the inner-most radii

Industrial Diamond Pixel Module Production



- Work done as part of ATLAS IBL sensor qualification process
- Plan to use 24 Diamond IBL modules as enhanced beam monitor

Properties of Diamond and Silicon

Property	Diamond	Silicon	1
Band gap [eV]	5.5	1.12	1
Breakdown field [V/cm]	107	3×10 ⁵	1
Intrinsic resistivity @ R.T. [Ω cm]	> 1011	2.3×10 ⁵	© Low leakage
Intrinsic carrier density [cm ⁻³]	< 10 ³	1.5×10 ¹⁰	
Electron mobility [cm²/Vs]	1900	1350	© Fast signal
Hole mobility [cm²/Vs]	2300	480	
Saturation velocity [cm/s]	1.3(e)-1.7(h)x 107	$1.1(e)-0.8(h) \times 10^7$	1
Density [g/cm³]	3.52	2.33	1
Atomic number - Z	6	14	1
Dielectric constant - ε	5.7	11.9	© Low capacitance
Displacement energy [eV/atom]	43	13-20	© Radiation hard
Thermal conductivity [W/m.K]	~2000	150	© Heat spreader
Energy to create e-h pair [eV]	13	3.61	1
Radiation length [cm]	12.2	9.36	
Spec. Ionization Loss [MeV/cm]	6.07	3.21	1
Aver. Signal Created / 100 µm [eo]	3602	8892	® Low signal
Aver. Signal Created / 0.1 X ₀ [e ₀]	4401	8323]